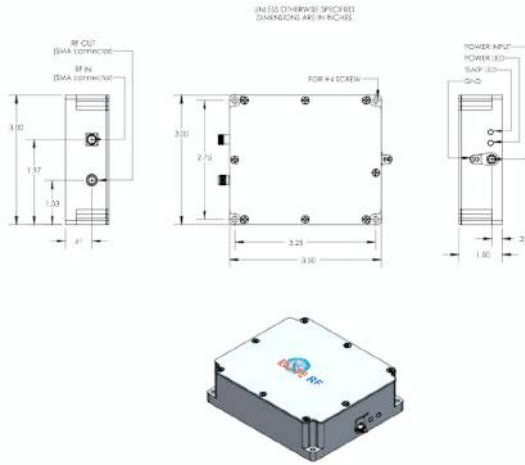


General Description:

This system is a broadband power amplifier designed for CW/Digital/Pulse signals and general-purpose amplification. Using advanced high power density LDMOS and GaN semiconductor devices, these high-performance amplifiers achieve high efficiency, high gain, and wide dynamic range. Like all Elite RF amplifiers, the product comes with an industry leading **5-year warranty**



Features

40 – 3000 MHz
22 dBm
26 dB gain
Class A
15 VDC

Indicator options

DC Power
Temp Fault

Protections

Thermal Overload
Over Voltage
Reverse Polarity

ELECTRICAL SPECIFICATIONS

Parameter	Symbol	Min	Typ	Max	Unit
Frequency Range	BW	40		3000	MHz
Output Power CW	Psat		25		dBm
Output Power at 1 dB Compression	P1dB		22		dBm
Small Signal Gain	Gp	38 @ 40 MHz	26	21 @ 3 GHz	dB
Gain Flatness	Delta Gp 1		N/A		dB
Input VSWR	S11		2:1		-
IMD @ 2 GHz @ 10 dBm/ tone	IP3		40		dBm
Harmonics at 18 dBm	H		-20		dBc
Spurious Signals	Spur		-60		dBc
Operating Voltage	VDC	14	15	16	VDC
DC Current	Current		200		mA
Class of Operation	C		A		Class
Noise Figure	NF		0.6		dB
Gain Adjustment Range	GA		N/A		dB

ENVIRONMENTAL CHARACTERISTICS

Parameter	Symbol	Min	Typ	Max	Unit
Operating Case Temperature	Tc	-20		+60	Deg C
Storage Temperature	Tstg	-40		+85	Deg C
Relative Humidity (non-condensing)	RH			95	%
Altitude	ALT			10,000	Feet
Vibration/Shock	VI /SH				Normal Truck Transport

MECHANICAL CHARACTERISTICS

Parameter	Symbol	Min	Typ	Max	Unit
Dimensions	Dim		3.5 x 3.0 x 1.0		Inches
Weight	Wt.		1		lbs.
Connectors In/Out	RF Conn		SMA/SMA		-
Cooling	Th		Convection		-